Vishay Semiconductors

Standard SMD LED PLCC-2



DESCRIPTION

SHA

This device has been designed to meet the increasing demand for AllnGaP technology.

The package of the TLME310. is the PLCC-2 (equivalent to a size B tantalum capacitor).

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

PRODUCT GROUP AND PACKAGE DATA

• Product group: LED

- Package: SMD PLCC-2
- · Product series: standard
- Angle of half intensity: ± 60°

FEATURES

- SMD LED with exceptional brightness
- Luminous intensity categorized
- Compatible with automatic placement equipment
- EIA and ICE standard package
- Compatible with infrared, vapor phase and wave solder processes according to CECC
- Available in 8 mm tape
- Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- Luminous intensity ratio in one packaging unit $I_{Vmax}/I_{Vmin} \leq 1.6$
- Lead (Pb)-free device

APPLICATIONS

- Automotive: backlighting in dashboards and switches
- Telecommunication: indicator and backlighting in telephone and fax
- Indicator and backlight for audio and video equipment
- · Indicator and backlight in office equipment
- Flat backlight for LCDs, switches and symbols
- General use

PARTS TABLE					
PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY			
TLME3100-GS08	Yellow, I _V > 25 mcd	AllnGaP on GaAs			
TLME3100-GS18	Yellow, I _V > 25 mcd	AllnGaP on GaAs			
TLME3101-GS08	Yellow, I _V = (32 to100) mcd	AllnGaP on GaAs			
TLME3105-GS08	Yellow, I _V = (50 to 160) mcd	AllnGaP on GaAs			

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ABSOLUTE MAXIMUM RATINGS ¹⁾ TLME310.					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
DC Forward current	$T_{amb} \le 60 \ ^{\circ}C$	١ _F	30	mA	
Surge forward current	t _p ≤ 10 μs	I _{FSM}	0.1	А	
Power dissipation	$T_{amb} \le 60 \ ^{\circ}C$	P _V	80	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	- 40 to + 100	°C	
Storage temperature range		T _{stg}	- 55 to + 100	°C	
Soldering temperature	t ≤ 5 s	T _{sd}	260	°C	
Thermal resistance junction/ ambient	mounted on PC board (pad size > 16 mm ²)	R _{thJA}	400	K/W	

Note:

¹⁾ $T_{amb} = 25 \ ^{\circ}C$, unless otherwise specified

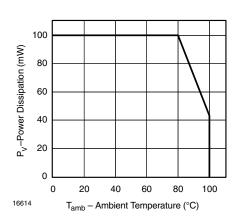
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity		TLME3100	Ι _V	25	50		mcd
	I _F = 10 mA	TLME3101	Ι _V	32		100	mcd
		TLME3105	Ι _V	50		160	mcd
Dominant wavelength	I _F = 10 mA		λ _d	581	588	594	nm
Peak wavelength	I _F = 10 mA		λ _p		590		nm
Angle of half intensity	I _F = 10 mA		φ		± 60		deg
Forward voltage	I _F = 20 mA		V _F		2	2.6	V
Reverse voltage	I _R = 10 μA		V _R	5			V
Junction capacitance	V _R = 0, f = 1 MHz		Ci		15		pF

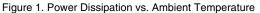
Note:

 $^{1)}$ T_{amb} = 25 °C, unless otherwise specified in one packing unit I_{Vmax}/I_{Vmin} ≤ 1.6

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified





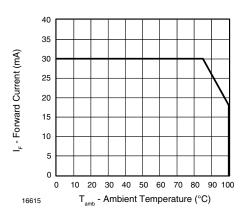


Figure 2. Forward Current vs. Ambient Temperature for InGaN



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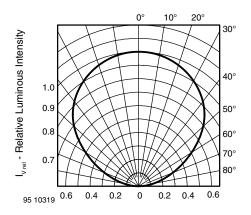


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

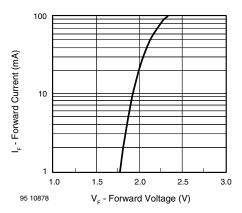


Figure 4. Forward Current vs. Forward Voltage

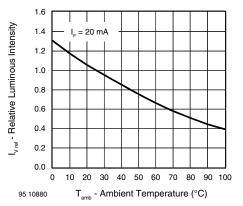


Figure 5. Rel. Luminous Intensity vs. Ambient Temperature

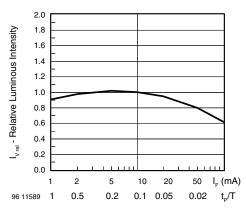


Figure 6. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

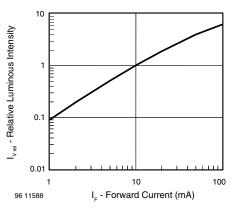
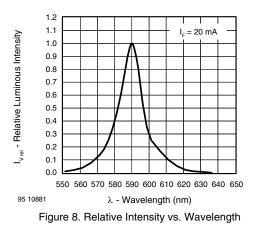


Figure 7. Relative Luminous Intensity vs. Forward Current



TLME310.

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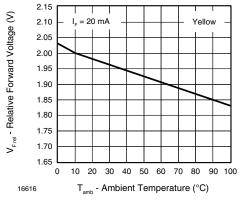
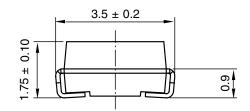
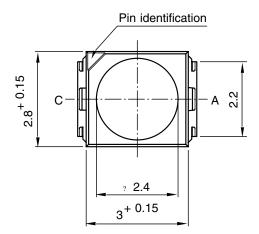


Figure 9. Forward Voltage vs. Ambient Temperature

PACKAGE DIMENSIONS in millimeters





Drawing-No.: 6.541-5025.01-4 Issue: 8; 22.11.05 95 11314-1

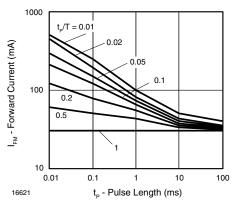
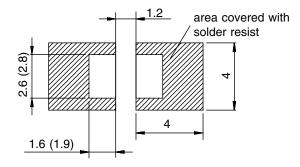


Figure 10. Forward Current vs. Pulse Length



Mounting Pad Layout





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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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